

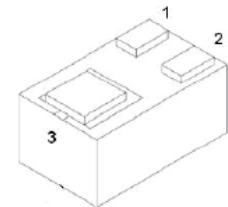
## P-Channel MOSFET

## 2KJ6057DFN

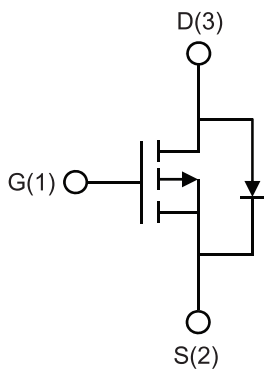
## ■ Features

- $V_{DS} (V) = -20V$
- $I_D = -2.5A$
- $R_{DS(ON)} = 97m\Omega @ V_{GS} = -4.5V$
- $R_{DS(ON)} = 125m\Omega @ V_{GS} = -2.5V$

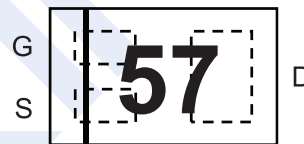
DFN1006-3



1.GATE  
2.SOURCE  
3.DRAIN



Circuit Diagram



Marking (Top View)

■ Absolute Maximum Ratings ( $T_A = 25^\circ C$  Unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	-20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	
Continuous Drain Current	$I_D$	-2.5	A
Pulsed Drain Current (Note 1)	$I_{DM}$	-10	
Power Dissipation	$P_D$	270	mW
Thermal Resistance, Junction- to-Ambient (Note 2)	$R_{\theta JA}$	420	$^\circ C/W$
Junction Temperature	$T_J$	150	$^\circ C$
Junction Storage Temperature Range	$T_{stg}$	-55 to 150	

Notes:

1. The maximum current rating is package limited.
2.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.

## P-Channel MOSFET

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■ Electrical Characteristics ( $T_A = 25^\circ\text{C}$  Unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D = -250\mu\text{A}$ , $V_{GS} = 0\text{V}$	-20			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -20\text{V}$ , $V_{GS} = 0\text{V}$			-1	$\mu\text{A}$
Gate-Body Leakage Current	$I_{GSS}$	$V_{DS} = 0\text{V}$ , $V_{GS} = \pm 12\text{V}$			$\pm 10$	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = -250\mu\text{A}$	-0.45		-0.9	V
Static Drain-Source On-Resistance (Note 3)	$R_{DS(on)}$	$V_{GS} = -4.5\text{V}$ , $I_D = -1\text{A}$		97	127	$\text{m}\Omega$
		$V_{GS} = -2.5\text{V}$ , $I_D = -1\text{A}$		125	168	
<b>Dynamic Characteristics (Note 4,5)</b>						
Input Capacitance	$C_{iss}$	$V_{GS} = 0\text{V}$ , $V_{DS} = -10\text{V}$ , $f = 1\text{MHz}$		248		$\text{pF}$
Output Capacitance	$C_{oss}$			30		
Reverse Transfer Capacitance	$C_{rss}$			28		
Total Gate Charge	$Q_g$	$V_{DS} = -10\text{V}$ , $I_D = -450\text{mA}$ , $V_{GS} = -4.5\text{V}$		3.0		$\text{nC}$
Gate Source Charge	$Q_{gs}$			0.2		
Gate Drain Charge	$Q_{gd}$			0.8		
<b>Switching Characteristics (Note 4,5)</b>						
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -10\text{V}$ , $I_D = -450\text{mA}$ , $R_G = 6\Omega$		5		$\text{ns}$
Turn-On Rise Time	$t_r$			5		
Turn-Off Delay Time	$t_{d(off)}$			53		
Turn-Off Fall Time	$t_f$			34		
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage	$V_{SD}$	$I_{SD} = -1\text{A}$ , $V_{GS} = 0\text{V}$			-1.1	V

## Notes

- Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$
- Essentially independent of operating temperature typical characteristics.
- Guaranteed by design, not subject to production testing

# P-Channel MOSFET

## 2KJ6057DFN

### Typical Characteristics

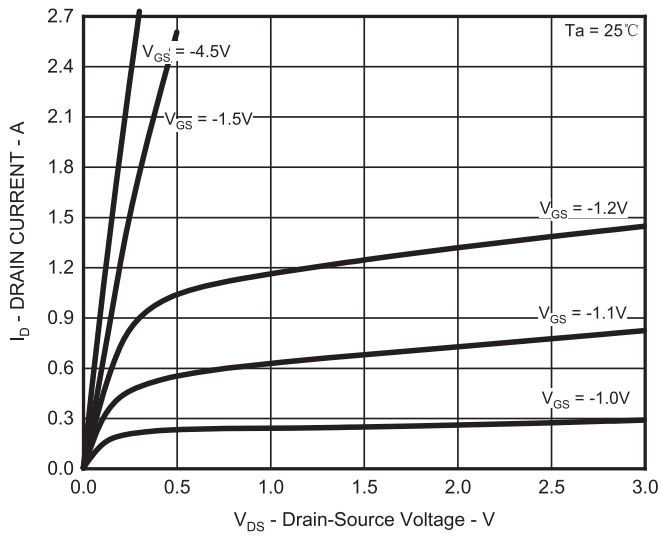


Fig.1 Output Characteristics

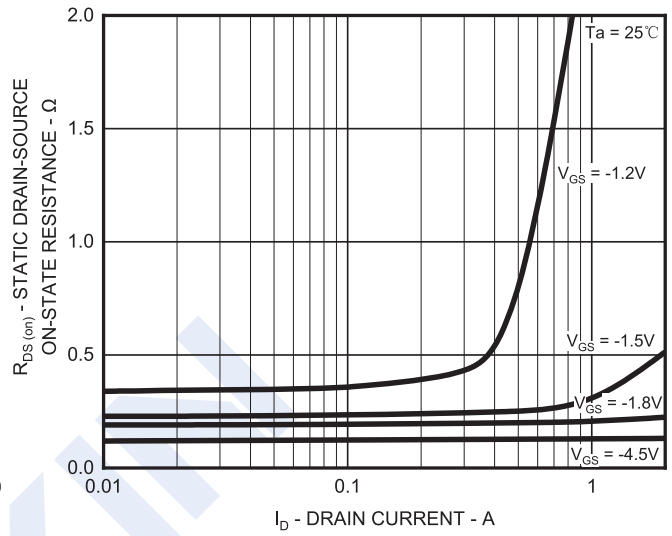


Fig.2 On-Resistance vs. Drain Current (I)

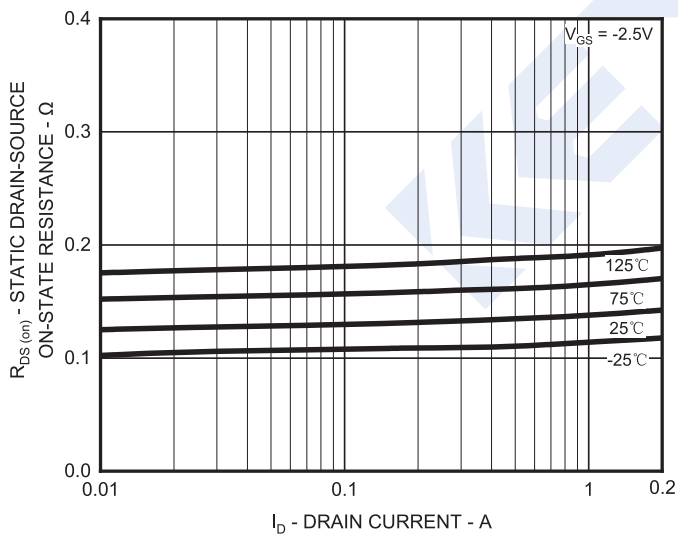


Fig.3 On-Resistance vs. Drain Current (II)

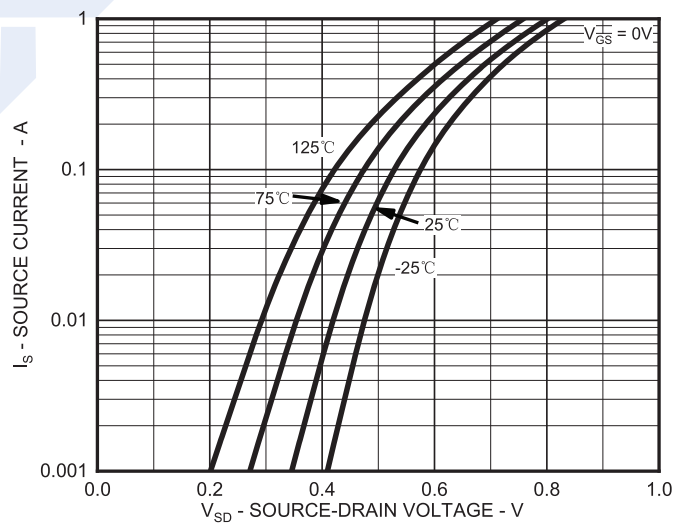


Fig.4 Diode Forward Voltage vs. Current

### P-Channel MOSFET

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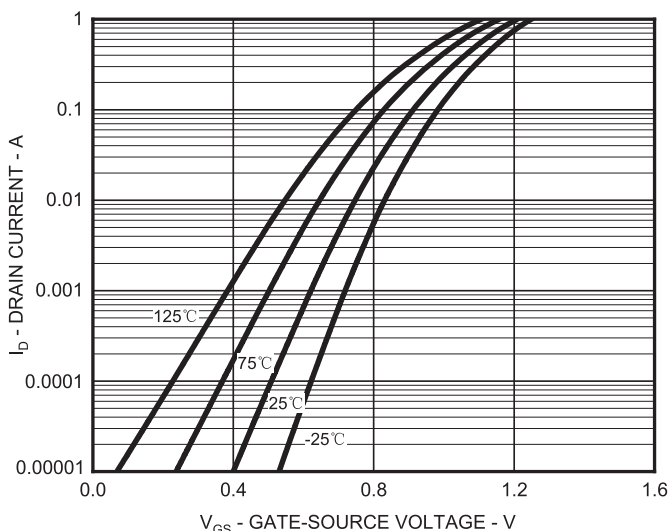


Fig.5 Typical Transfer Characteristic

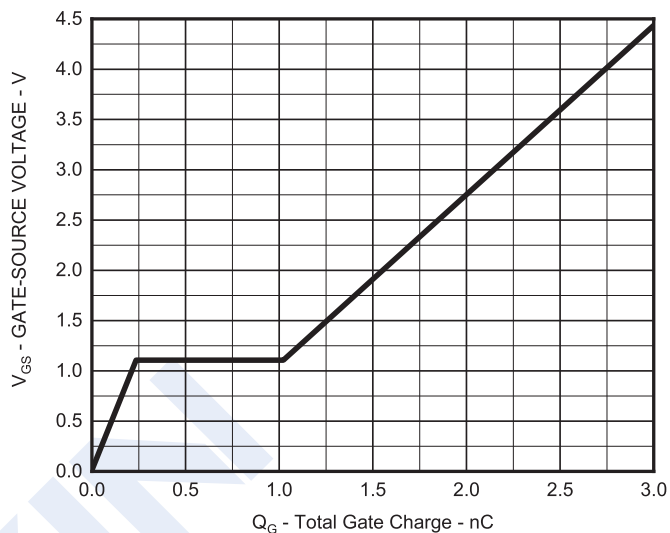


Fig.6 Gate Charge Characteristics

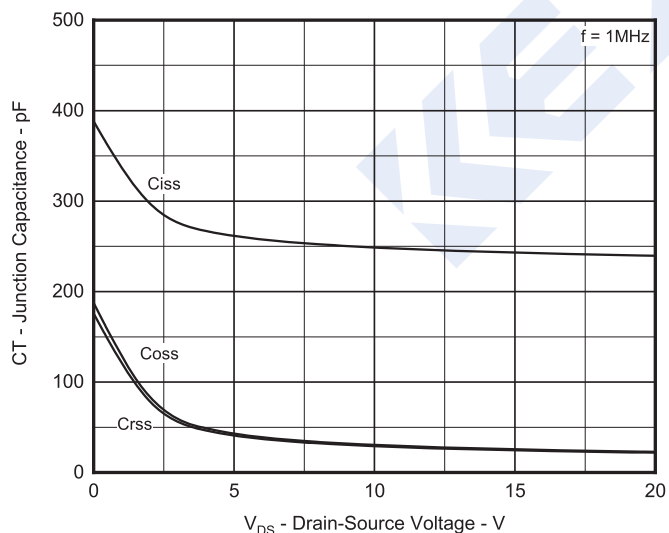
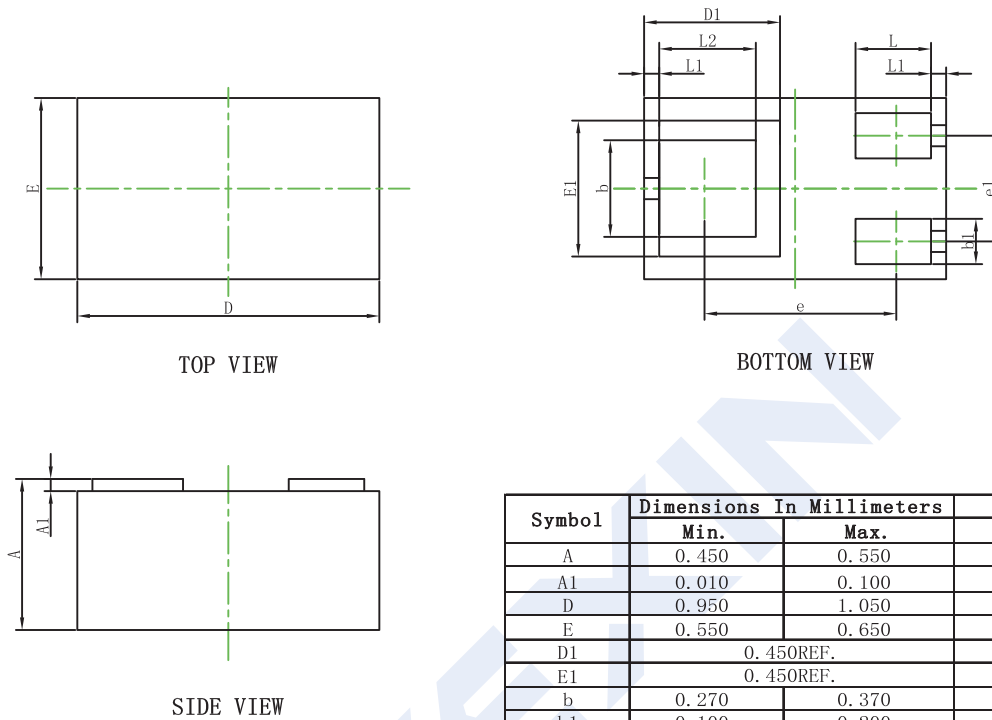


Fig.7 Typical Junction Capacitance

### P-Channel MOSFET

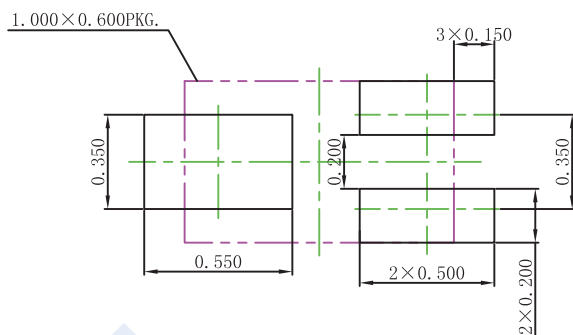
### 2KJ6057DFN

■ DFN1006-3 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.450	0.550	0.018	0.022
A1	0.010	0.100	0.000	0.004
D	0.950	1.050	0.037	0.041
E	0.550	0.650	0.022	0.026
D1	0.450REF.		0.018REF.	
E1	0.450REF.		0.018REF.	
b	0.270	0.370	0.011	0.015
b1	0.100	0.200	0.004	0.008
e	0.635REF.		0.025REF.	
e1	0.300	0.400	0.012	0.016
L	0.200	0.300	0.008	0.012
L1	0.050REF.		0.002REF.	
L2	0.270	0.370	0.011	0.015

■ DFN1006-3 Suggested Pad Layout

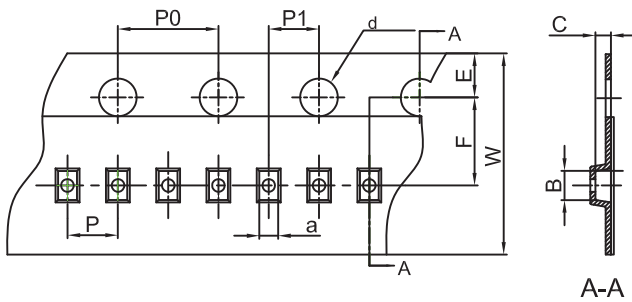


**Note:**

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.050$  mm.
3. The pad layout is for reference purposes only.

# DFN1006-3 Tape and Reel Data

## 1. DFN1006-3 Embossed Carrier Tape Configuration:

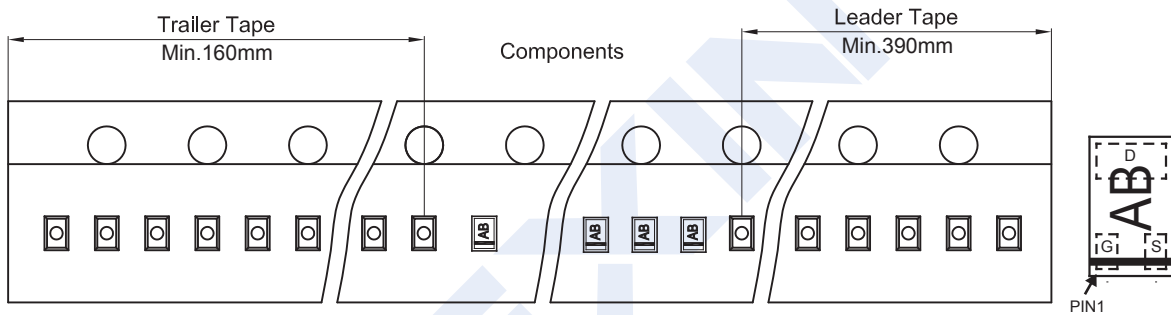


### Packaging Description:

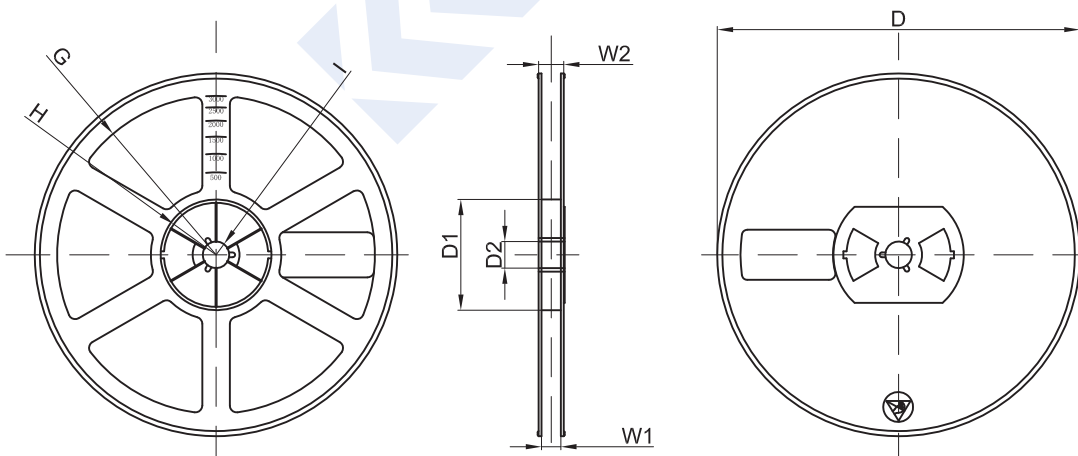
**DFN1006-3** parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 10,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
<b>DFN1006-3</b>	0.66	1.15	0.66	Ø1.50	1.75	3.50	4.00	2.00	2.00	8.00

## 2. DFN1006-3 Tape Leader and Trailer Configuration:



## 3. DFN1006-3 Reel Configuration:



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
10000 pcs	7 inch	100,000 pcs	182×182×135	400,000 pcs	386×386×150 *	

\* Which comes in different sizes depending on the number of parts shipped.